

1.5mm SIDE LOOK INFRARED EMITTING DIODE

Part Number: KM-4457F3C

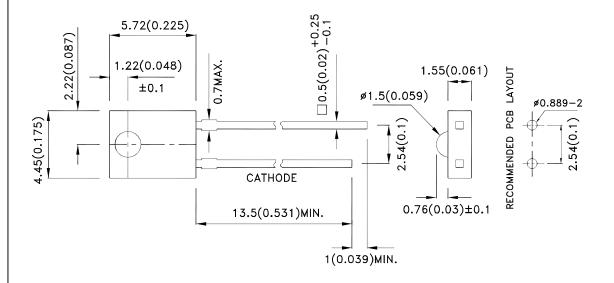
Features

- Side looking package.
- Mechanically and spectrally matched to the phototransistor.
- RoHS compliant.

Description

F3 Made with Gallium Arsenide Infrared Emitting diodes.

Package Dimensions



- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is $\pm 0.25(0.01")$ unless otherwise noted.
- Lead spacing is measured where the leads emerge from the package.
 The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.

SPEC NO: DSAB1977 APPROVED: WYNEC

REV NO: V.13A CHECKED: Allen Liu

DATE: AUG/16/2014 DRAWN: L.Q.Xie

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Selection Guide

Part No.	Dice	Po (mW/sr) [2] Lens Type @ 20mA			Viewing Angle [1]
			Min.	Тур.	201/2
I/M 4457500	F2 (CaAa)	Matan Class	3	7	700
KM-4457F3C	F3 (GaAs)	Water Clear		*5	- 70°

Notes:

- 1. 01/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
 2. Radiant Intensity/ luminous flux: +/-15%.

 * Radiant intensity value is traceable to the CIE127-2007 compliant national standards.

Electrical / Optical Characteristics at TA=25°C

Parameter	P/N	Symbol	Тур.	Max.	Units	Test Conditions	
Forward Voltage [1]	F3	VF	1.2	1.6	V	IF=20mA	
Reverse Current	F3	lR		10	uA	V _R = 5V	
Capacitance	F3	С	90		pF	VF=0V;f=1MHz	
Peak Spectral Wavelength	F3	λР	940		nm	IF=20mA	
Spectral Bandwidth	F3	Δλ1/2	50		nm	IF=20mA	

Note:

- Forward Voltage: +/-0.1V.
 Wavelength value is traceable to the CIE127-2007 compliant national standards.

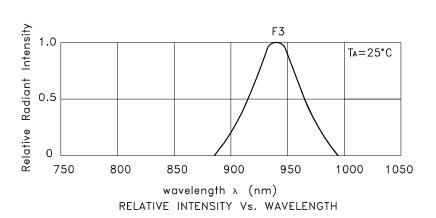
Absolute Maximum Ratings at TA=25°C

Parameter	Symbol	F3	Units		
Power dissipation	PD	80	mW		
DC Forward Current	lF	50	mA		
Peak Forward Current [1]	iFS	1.2	А		
Reverse Voltage	VR	5	V		
Operating Temperature	ТА	-40 To +85 °C			
Storage Temperature	Тѕтс	-40 To +85	°C		
Lead Solder Temperature [2]		260°C For 3 Seconds			
Lead Solder Temperature [3]		260°C For 5 Seconds			

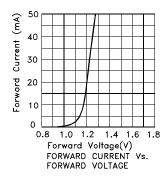
- 1. 1/100 Duty Cycle, 10µs Pulse Width.
- 2. 2mm below package base.
 5mm below package base.

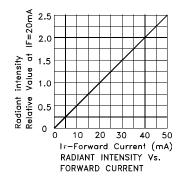
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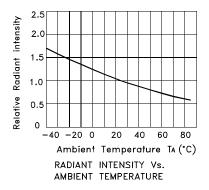
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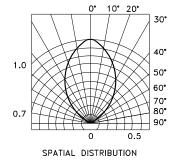


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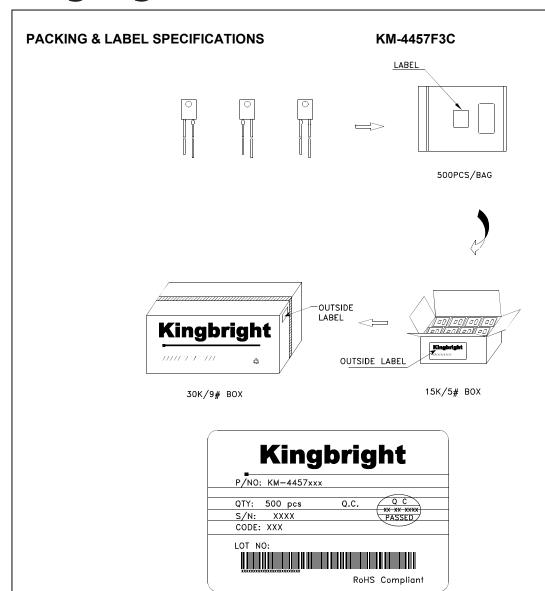






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